



ULTRA FAST RECOVERY RECTIFIER DIODES

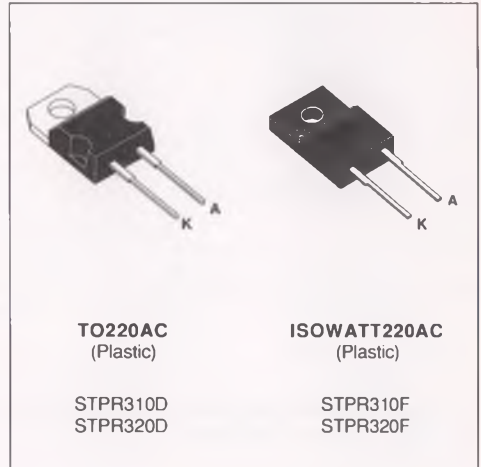
FEATURES

- SUITED FOR SMPS
- LOW LOSSES
- LOW FORWARD AND REVERSE RECOVERY TIME
- HIGH SURGE CURRENT CAPABILITY
- HIGH AVALANCHE ENERGY CAPABILITY

DESCRIPTION

Low cost single chip rectifier suited for switchmode power supply and high frequency DC to DC converters.

Packaged in TO220AC and ISOWATT220AC, this device is intended for use in low voltage, high frequency inverters, free wheeling and polarity protection applications.



ABSOLUTE RATINGS (limiting values)

Symbol	Parameter		Value	Unit	
I _{F(RMS)}	RMS Forward Current		10	A	
I _{F(AV)}	Average Forward Current $\delta = 0.5$	TO220AC	T _c = 125°C	3	A
		ISOWATT220AC			
I _{FSM}	Surge Non Repetitive Forward Current		T _p = 10 ms Sinusoidal	30	A
T _{stg} T _j	Storage and Junction Temperature Range		- 65 to + 150 - 65 to + 150		°C

Symbol	Parameter	STPR		Unit
		310D 310F	320D 320F	
V _{RRM}	Repetitive Peak Reverse Voltage	100	200	V

THERMAL RESISTANCE

Symbol	Parameter		Value	Unit
R _{th(j-c)}	Junction-case	TO220AC	6.5	°C/W
		ISOWATT220AC	8.5	

ELECTRICAL CHARACTERISTICS

STATIC CHARACTERISTICS

Symbol	Tests Conditions		Min.	Typ.	Max.	Unit
I _R *	T _j = 25°C	V _R = V _{RRM}			50	μA
	T _j = 100°C				0.5	mA
V _F **	T _j = 125°C	I _F = 3 A			0.99	V
	T _j = 125°C	I _F = 6 A			1.20	
	T _j = 25°C	I _F = 6 A			1.25	

Pulse test : * t_p = 5 ms, duty cycle < 2 %
 ** t_p = 380 μs, duty cycle < 2%

RECOVERY CHARACTERISTICS

Symbol	Tests Conditions			Min.	Typ.	Max.	Unit
t _{rr}	T _j = 25°C	I _F = 0.5 A	I _R = 1 A I _{rr} = 0.25 A			30	ns
t _{fr}	T _j = 25°C	I _F = 1 A	t _r = 10 ns V _{FR} = 1.1 x V _F		20		ns
V _{FP}	T _j = 25°C	I _F = 1 A	t _r = 10 ns		3		V

To evaluate the conduction losses use the following equation :
 P = 0.78 x I_F(AV) + 0.070 I_F²(RMS)

Fig.1 : Average forward power dissipation versus average forward current.

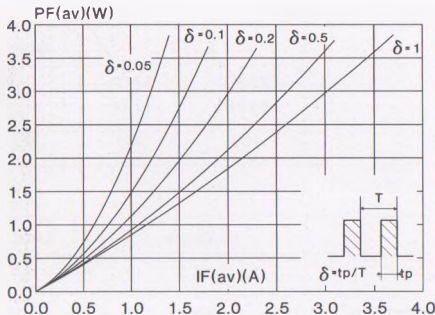


Fig.2 : Peak current versus form factor.

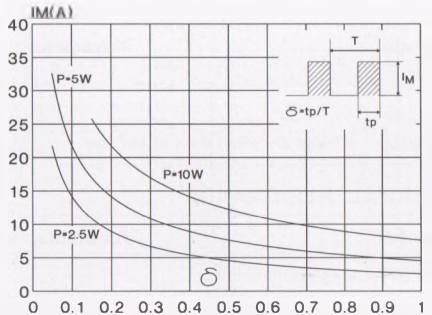


Fig.3 : Average current versus ambient temperature. (duty cycle : 0.5) (TO220AC)

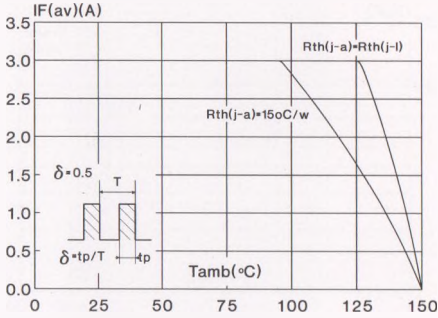


Fig.4 : Average current versus ambient temperature. (duty cycle : 0.5) (ISOWATT220AC)

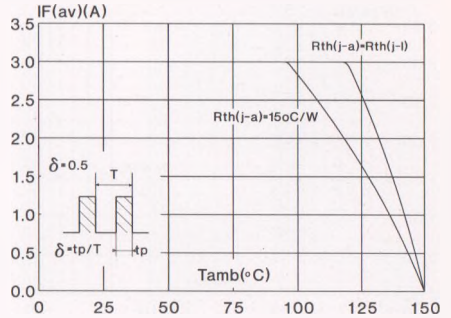


Fig.5 : Non repetitive surge peak forward current versus overload duration. (Maximum values) (TO220AC)

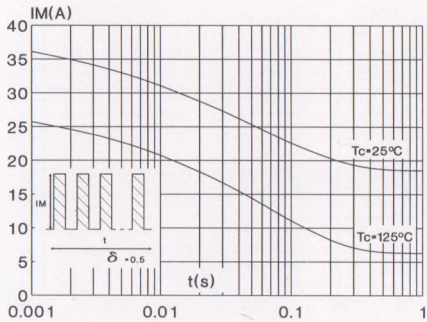


Fig.6 : Non repetitive surge peak forward current versus overload duration. (Maximum values) (ISOWATT220AC)

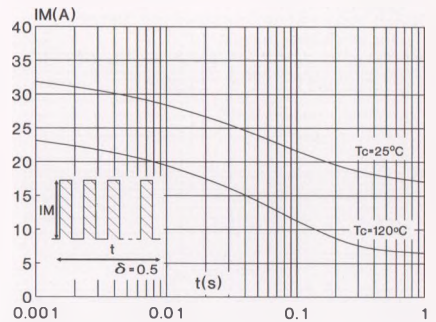


Fig.7 : Relative variation of thermal transient impedance junction to case versus pulse duration. (TO220AC)

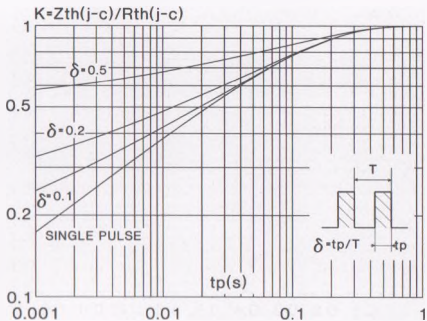


Fig.8 : Relative variation of thermal transient impedance junction to case versus pulse duration. (ISOWATT220AC)

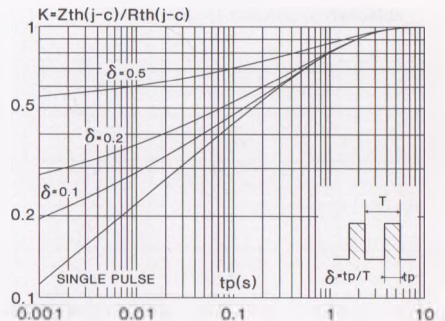


Fig.9 : Forward voltage drop versus forward current. (Maximum values)

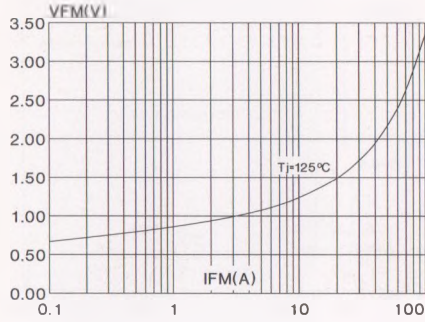


Fig.10 : Junction capacitance versus reverse voltage applied. (Typical values)

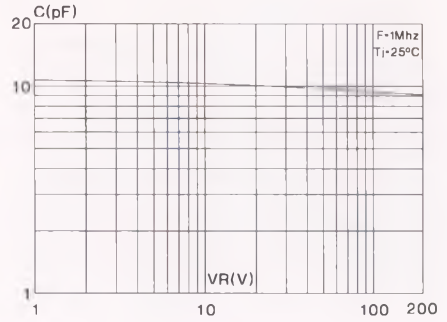


Fig.11 : Recovery charge versus dI_F/dt .

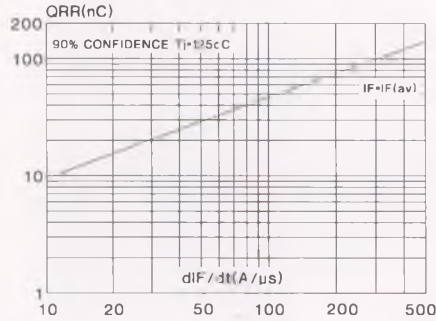


Fig.12 : Peak reverse current versus dI_F/dt .

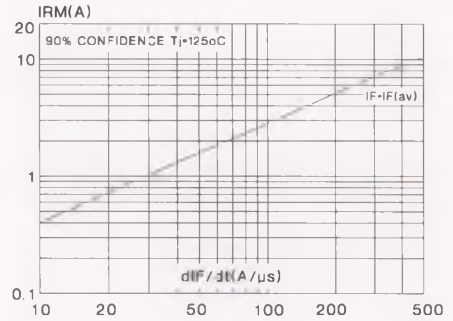


Fig.13 : Dynamic parameters versus junction temperature.

